

Switchmode Full Plastic Dual Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. The proprietary barrier technology allows for reliable operation up to 175°C junction temperature. Typical application are in switching Mode Power Supplies such as adaptors, DC/DC converters, free-wheeling and polarity protection diodes.

Features

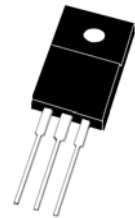
- * Low Forward Voltage.
- * Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- * Low Power Loss & High efficiency.
- * 175°C Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used carries Underwriters Laboratory Flammability Classification 94V-0



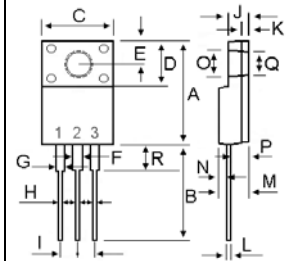
* In compliance with EU RoHs 2002/95/EC directives

**SCHOTTKY BARRIER
RECTIFIERS**

**30 AMPERES
200 VOLTS**



ITO-220AB



DIM	MILLIMETERS	
	MIN	MAX
A	14.90	15.15
B	13.35	13.55
C	10.00	10.10
D	6.55	6.65
E	2.65	2.75
F	1.55	1.65
G	1.15	1.25
H	0.55	0.65
I	2.50	2.60
J	3.00	3.20
K	1.10	1.20
L	0.55	0.65
M	4.40	4.60
N	1.15	1.25
O	3.35	3.45
P	2.65	2.75
Q	3.15	3.25
R	3.60	3.80

MAXIMUM RATINGS

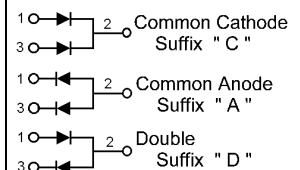
Characteristic	Symbol	MBRF30200CK	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	200	V
Working Peak Reverse Voltage	V_{RWM}		
DC Blocking Voltage	V_R		
RMS Reverse Voltage	$V_{R(RMS)}$	140	V
Average Rectifier Forward Current (per diode)	$I_{F(AV)}$	15	A
Total Device (Rated V_R , $T_C=125^\circ\text{C}$)		30	
Peak Repetitive Forward Current (Rate V_R , Square Wave, 20kHz)	I_{FM}	30	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfwave, single phase, 60Hz)	I_{FSM}	250	A
Operating and Storage Junction Temperature Range	T_J, T_{STG}	-65 to +175	°C

THERMAL RESISTANCES

Typical Thermal Resistance junction to case (per device)	$R_{\theta jc}$	3.8	°C/w
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ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	MBRF30200CK	Unit
Maximum Instantaneous Forward Voltage (per diode) ($I_F = 15 \text{ Amp } T_C = 25^\circ\text{C}$) ($I_F = 15 \text{ Amp } T_C = 125^\circ\text{C}$)	V_F	0.95	V
		0.85	
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^\circ\text{C}$) (Rated DC Voltage, $T_C = 125^\circ\text{C}$)	I_R	0.01	mA
		10	



MBRF30200CK

FIG-1 FORWARD CURRENT DERATING CURVE

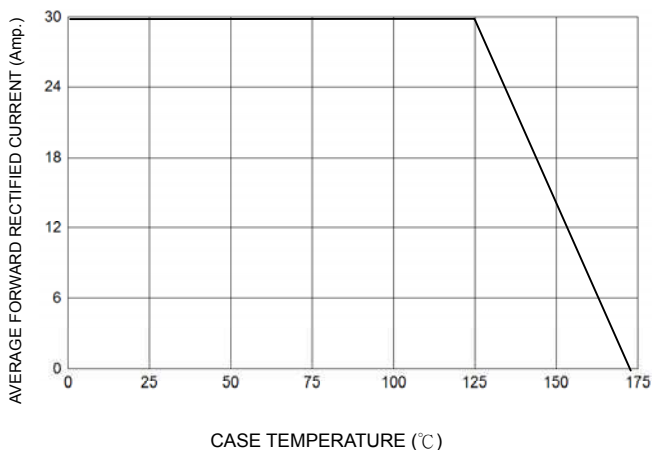


FIG-2 TYPICAL FORWARD CHARACTERISTICS

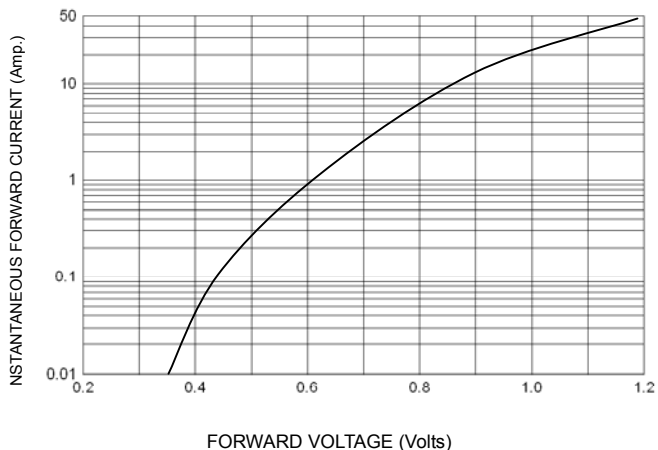


FIG-3 TYPICAL REVERSE CHARACTERISTICS

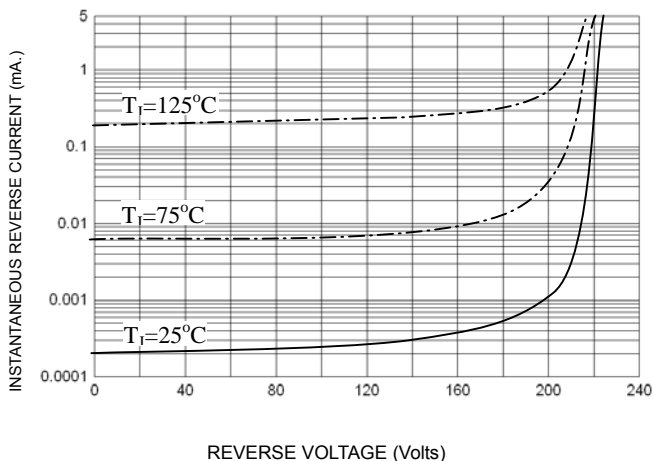


FIG-4 TYPICAL JUNCTION CAPACITANCE

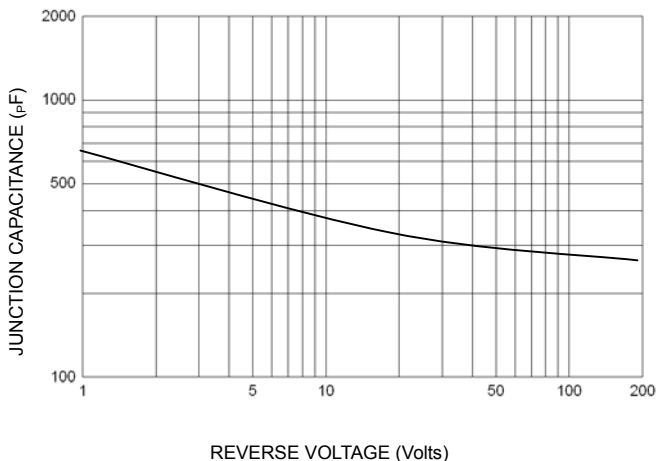


FIG-5 PEAK FORWARD SURGE CURRENT

